

PowderMEMS Technology – Microfluidics

Porous 3D Microcomponents for Innovative Microsystems

Wafer with porous
microfluidic channels

Fraunhofer ISIT
PowderMEMS enables
unique advantages for
your MEMS solutions

- 3D structures up to 600 μm thickness on wafer-level
- Precise structural dimensions between 20 μm and 4000 μm
- Numerous degrees of freedom, conductive, thermal and magnetic properties, porosity and 3D-geometry
- Surface finish of porous structures adjustable by atomic layer deposition (ALD) technology
- Advantages compared to other manufacturing techniques: low process temperatures, thermally and chemically resistant structures, BEOL-compatible pre- and post-processing

PowderMEMS Technology

Fraunhofer ISIT has developed a patented process to create three-dimensional porous microstructures from a multitude of materials on wafer-level. The technology enables the integration of porous structures in microfluidic channels, on electrodes, as thermal insulation and numerous other features for next-generation microsystems. PowderMEMS accesses the third dimension on wafer-level for the design of porous microstructures with decisive advantages compared to other techniques like sintering or polymeric binding. Various parameters can be taken advantage of, such as the choice of powder material, the surface finish, the creation of three-dimensional shapes and the ability to pre- and post-process with established MEMS cleanroom technologies.

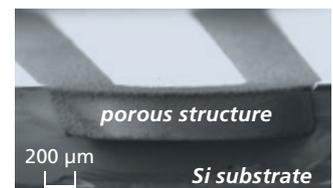
Examples of Applications: Lab-on-a-Chip / Sensors

- Filters / Mixers / Scaffolding
- Support for enzyme immobilization / Enzyme electrodes
- Large surface area catalyst for microreactors / Gas sensors
- Microscale thermal insulation of MEMS structures

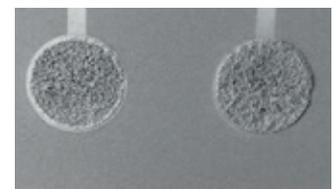
PowderMEMS Technical Specifications

Structure lateral dimensions	20 μm to 4000 μm
Structure thickness	40 μm to 600 μm
Applicable powdered materials	Metals, Ceramics, Composites, etc...
Surface finishes (ALD)	Oxides and Nitrides e.g. SiO_2 , SnO_2^* , Al_2O_3 , Si_3N_4^*
Process temperature	75 $^\circ\text{C}$ to 300 $^\circ\text{C}$
Compatible with cleanroom post-processing	yes

*ALD process planned/under development



Detail of permeable
porous channel



Porous electrodes for
electrochemical sensors

Contact us to explore the advantages
of our technology in your application

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